



DTB713Z series

PNP -200mA -30V Digital Transistors (Bias Resistor Built-in Transistors)

Datasheet

Parameter	Value
V_{CC}	-30V
$I_{C(MAX.)}$	-200mA
R_1	1.0k Ω
R_2	10k Ω

●Features

- 1) Built-In Biasing Resistors
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary NPN Types :DTD713Z series
- 6) Lead Free/RoHS Compliant.



●Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

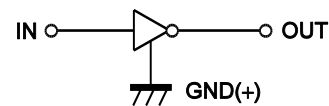
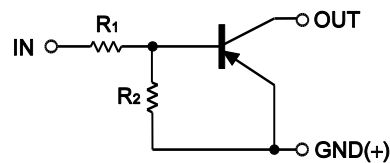
●Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTB713ZM	VMT3	1212	T2L	180	8	8,000	P11
DTB713ZE	EMT3	1616	TL	180	8	3,000	P11

●Outline

VMT3  DTB713ZM (SC-105AA)	EMT3  DTB713ZE SOT-416 (SC-75A)
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●Inner circuit



●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V_{CC}	-30	V
Input voltage	V_{IN}	-10 to +5	V
Collector current	$I_{C(MAX.)}^{*1}$	-200	mA
Power dissipation	P_D^{*2}	150	mW
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input voltage	$V_{I(off)}$	$V_{CC} = -5V, I_O = -100\mu A$	-	-	-0.3	V
	$V_{I(on)}$	$V_O = -0.3V, I_O = -20mA$	-2.5	-	-	
Output voltage	$V_{O(on)}$	$I_O / I_I = -50mA / -2.5mA$	-	-0.07	-0.3	V
Input current	I_I	$V_I = -5V$	-	-	-6.4	mA
Output current	$I_{O(off)}$	$V_{CC} = -30V, V_I = 0V$	-	-	-0.5	μA
DC current gain	G_I	$V_O = -2V, I_O = -100mA$	140	-	-	-
Input resistance	R_1	-	0.7	1.0	1.3	k Ω
Resistance ratio	R_2/R_1	-	8	10	12	-
Transition frequency	f_T^{*1}	$V_{CE} = -10V, I_E = 5mA,$ $f = 100MHz$	-	260	-	MHz

*1 Characteristics of built-in transistor

*2 Each terminal mounted on a reference footprint

●Electrical characteristic curves(Ta = 25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

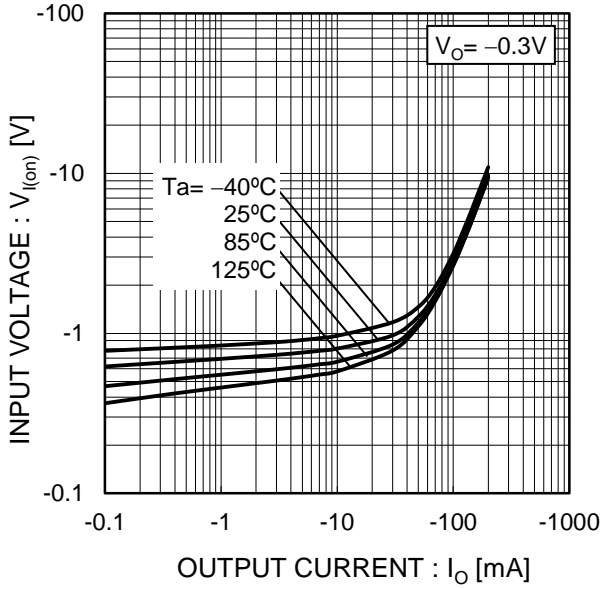


Fig.2 Output current vs. input voltage (OFF characteristics)

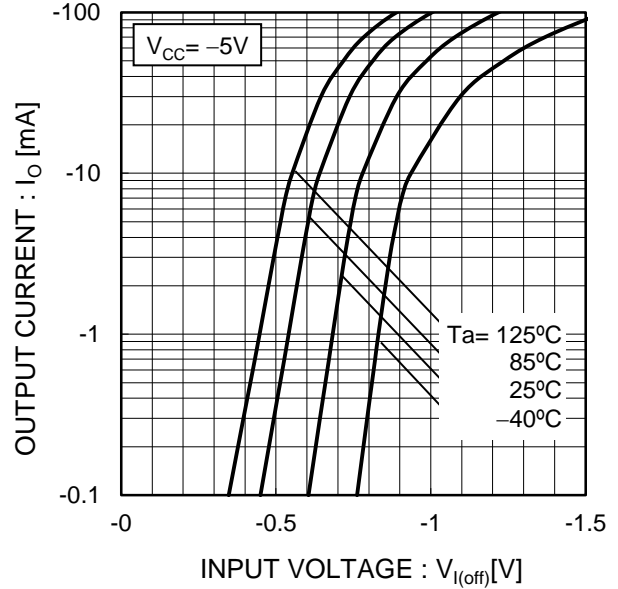


Fig.3 Output current vs. output voltage

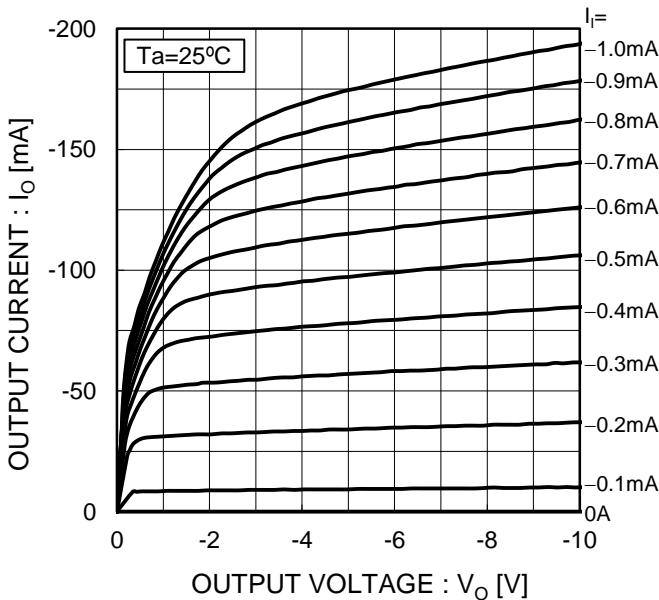
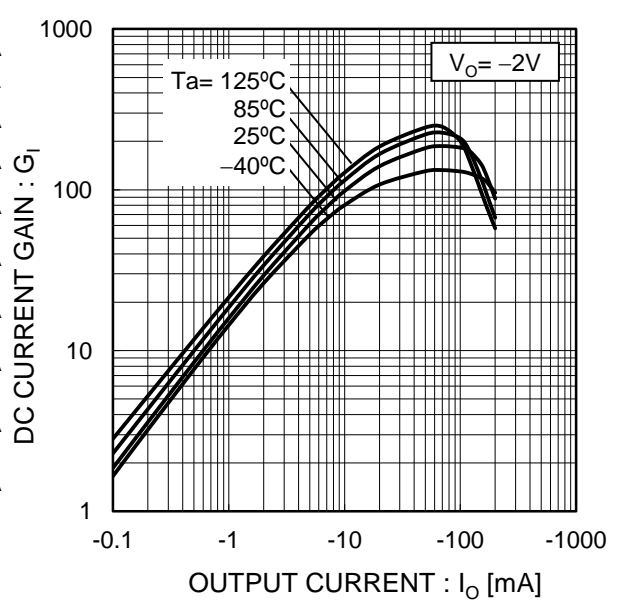
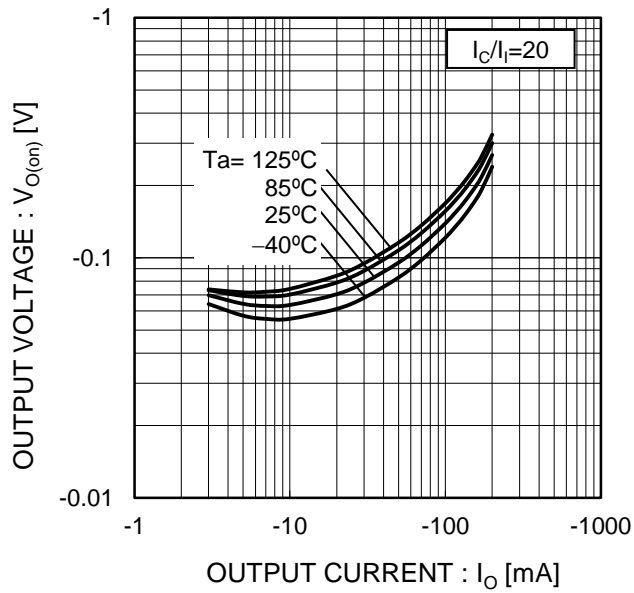


Fig.4 DC current gain vs. output current



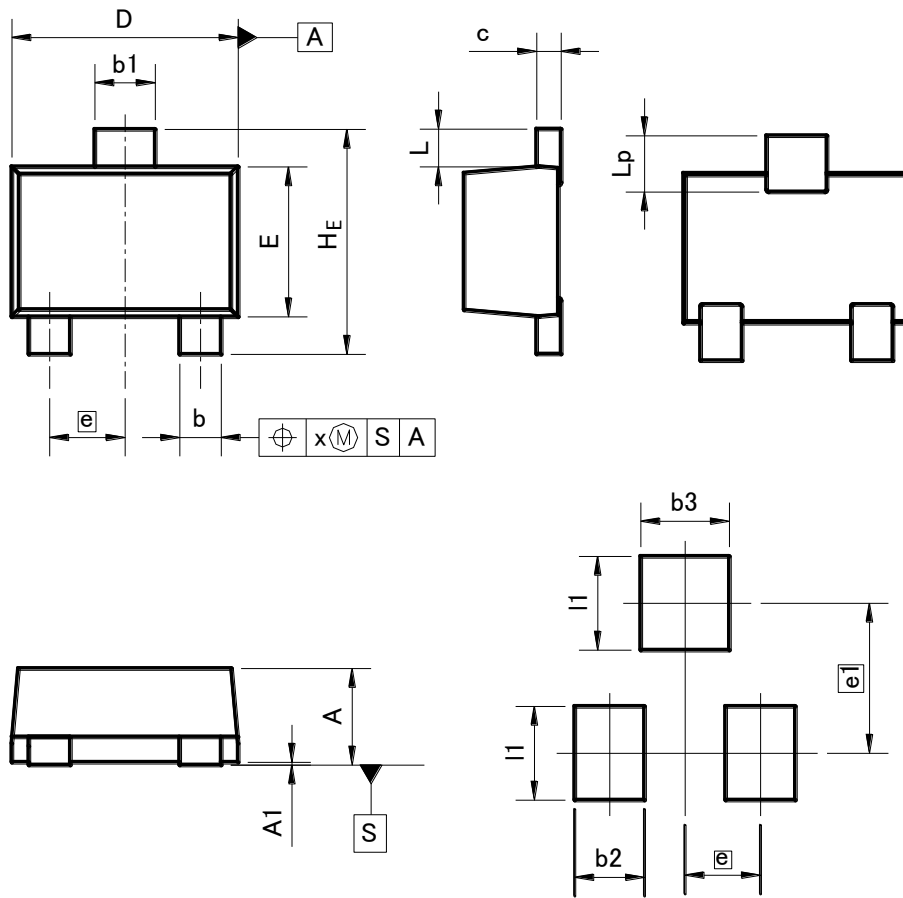
●Electrical characteristic curves($T_a = 25^\circ\text{C}$)

Fig.5 Output voltage vs. output current



●Dimensions (Unit : mm)

VMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

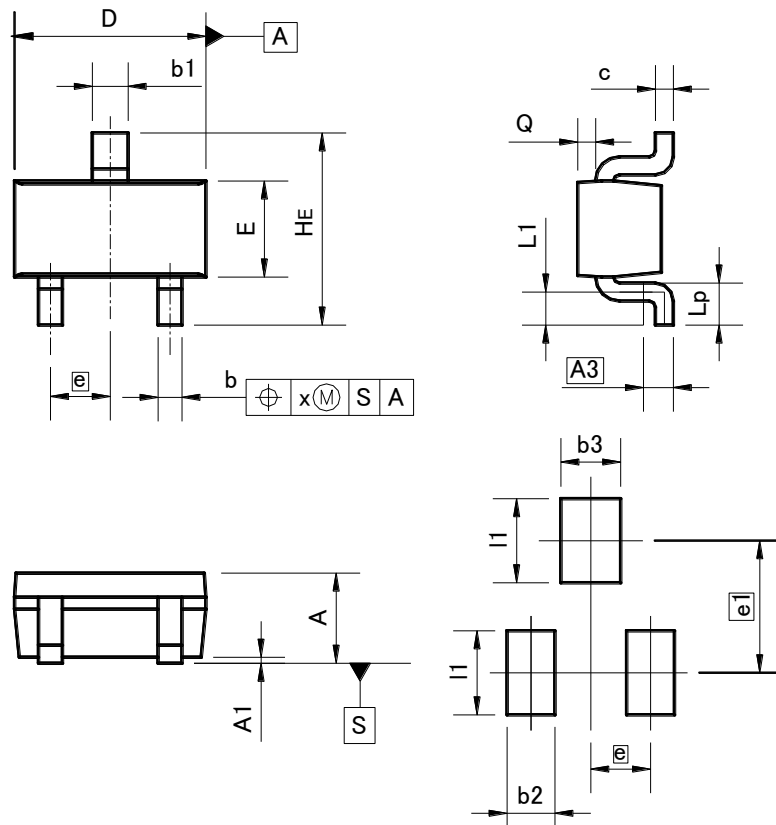
DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
c	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
e	0.40		0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.37	-	0.015
b3	-	0.47	-	0.019
e1	0.80		0.031	
l1	-	0.50	-	0.020

Dimension in mm / inches

●Dimensions (Unit : mm)

EMT3



Pattern of terminal position areas
[Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
c	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
e	0.50		0.020	
HE	1.40	1.80	0.055	0.071
L1	0.10	-	0.004	-
Lp	0.15	-	0.006	-
Q	0.05	0.25	0.002	0.010
x	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	-	0.40	-	0.016
b3	-	0.50	-	0.020
e1	1.10		0.043	
l1	-	0.70	-	0.028

Dimension in mm / inches

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